

TS861, TS862, TS864

Rail-to-rail micropower BiCMOS comparators

Datasheet -production data

Features

- Ultra low current consumption (6 µA/comp. at V_{CC} = 2.7 V)
- Rail-to-rail CMOS inputs
- Push-pull outputs
- Supply operation from 2.7 to 10 V
- Low propagation delay
- ESD protection (2 kV)
- Latch-up immunity (class A)
- Available in SOT23-5 micropackage, SO-8, SO-14,TSSOP8, and TSSOP14 package

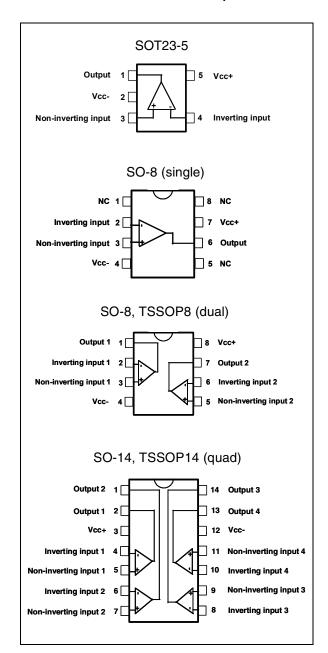
Applications

- Battery powered systems such as alarms
- Portable communication systems
- Smoke/gas/fire detectors
- Portable computers

Description

The TS86x device (single, dual and quad) is a rail-to-rail comparator characterized for 2.7 to 10 V operation over -40 °C to +85 °C temperature ranges. It exhibits an excellent speed-to-power ratio, featuring a current consumption of 6 μ A per comparator and a response time of 500 ns at 2.7 V for a 100 mV overdrive.

Due to its ultra low power consumption and its availability in a tiny package, the TS86x comparator family is perfectly suited to battery-powered systems. The output stage is designed with a push-pull structure allowing a direct connection to the microcontroller without additional pull-up resistors.



November 2012 Doc ID 6422 Rev 3 1/19

This is information on a product in full production.

Absolute maximum ratings and operating conditions

Table 1. **Absolute maximum ratings**

Symbol	Parameter	Value	Unit
V _{CC}	Supply voltage ⁽¹⁾	12	V
V _{ID}	Differential input voltage ⁽²⁾	±12	V
V _{IN}	Input voltage range ⁽³⁾	-0.3 to 12.3	V
R _{THJA}	Thermal resistance junction-to-ambient ⁽⁴⁾ SOT23-5 SO-8 SO-14 TSSOP8 TSSOP14	250 125 105 120 100	°C/W
R _{THJC}	Thermal resistance junction-to-case ⁽⁴⁾ SOT23-5 SO-8 SO-14 TSSOP8 TSSOP14	81 40 31 37 32	°C/W
T _{STG}	Storage temperature range	-65 to +150	°C
T _J	Maximum junction temperature	150	°C
T _{LEAD}	Lead temperature (soldering, 10 sec.)	260	°C
ESD	Human body model (HBM) ⁽⁵⁾ Machine model (MM) ⁽⁶⁾	2 200	kV V
	Latch-up immunity	Class A	

- 1. All voltages values, except differential voltage are with respect to network terminal.
- 2. Differential voltages are non-inverting input terminal with respect to the inverting input terminal.
- 3. The magnitude of input and output voltages must never exceed $\mbox{V}_{\mbox{\scriptsize CC}}$ +0.3 V.
- Short-circuits can cause excessive heating. These values are typical.
- 5. Human body model: a 100 pF capacitor is charged to the specified voltage, then discharged through a 1.5 k Ω resistor between two pins of the device. This is done for all couples of connected pin combinations while the other pins are floating.
- 6. Machine model: a 200 pF capacitor is charged to the specified voltage, then discharged directly between two pins of the device with no external series resistor (internal resistor < 5 Ω). This is done for all couples of connected pin combinations while the other pins are floating.

Operating conditions Table 2.

Symbol	Parameter	Value	Unit
V _{CC}	Supply voltage	2.7 to 10	V
V _{ICM}	Common mode input voltage range	V_{CC}^- - 0.3 to V_{CC}^+ + 0.3	V
T _{Oper}	Operating free air temperature range	-40 to + 85	°C

2/19 Doc ID 6422 Rev 3

2 Electrical characteristics

Table 3. Electrical characteristics at V_{CC} = 2.7 V, T_{amb} = 25 °C (unless otherwise specified)

Symbol	Parameter	Min.	Тур.	Max.	Unit
V _{IO}	Input offset voltage $TS861/2/4$ $T_{min} < T < T_{max}$ $TS861/2/4A$ $T_{min} < T < T_{max}$		3	15 18 7 10	mV
ΔV _{IO}	Input offset voltage drift		6		μV/°C
I _{IO}	Input offset current ⁽¹⁾ $T_{min} < T < T_{max}$		1	150 300	pА
I _{IB}	Input bias current ⁽¹⁾ $T_{min} < T < T_{max}$		1	300 600	pА
V _{OH}	High level output voltage $I_{SOURCE} = 2.5 \text{ mA} $ $T_{min} < T < T_{max}$	2.35 2.15	2.45		٧
V _{OL}	Low level output voltage $I_{SINK} = 2.5 \text{ mA} $ $T_{min} < T < T_{max}$		0.2	0.35 0.45	V
A _{VD}	Large signal voltage gain ⁽²⁾		240		dB
CMR	Common mode rejection ratio 0 < V _{ICM} < 2.7 V		65		dB
SVR	Supply voltage rejection ratio 0 < V _{CC} < 10 V		80		dB
I _{CC}	Supply current per comparator No load, output low No load, output high		6 8	12 14	μА
T _{PLH}	Propagation delay from output low to output high $V_{ICM} = 1.35 \text{ V}$, $f = 10 \text{ kHz}$, $C_L = 50 \text{ pF}$ Overdrive = 10 mV Overdrive = 100 mV		1.5 0.6		μs
T _{PHL}	Propagation delay from output high to output low $V_{ICM} = 1.35 \text{ V}$, $f = 10 \text{ kHz}$, $C_L = 50 \text{ pF}$ Overdrive = 10 mV Overdrive = 100 mV		1.5 0.5		μs

Table 3. Electrical characteristics at V_{CC} = 2.7 V, T_{amb} = 25 °C (unless otherwise specified) (continued)

Symbol	Parameter	Min.	Тур.	Max.	Unit
T _F	Fall time $f = 10 \text{ kHz}, C_L = 50 \text{ pF}, \text{ overdrive} = 100 \text{ mV}$		20		ns
T _R	Rise time $f = 10 \text{ kHz}, C_L = 50 \text{ pF}, \text{ overdrive} = 100 \text{ mV}$		20		ns

- 1. Maximum values including unavoidable inaccuracies of the industrial tests.
- 2. Design evaluation.

Note: Limits are 100% production tested at 25 °C. Limits over temperature are guaranteed through correlation and by design.

Table 4. Electrical characteristics at V_{CC} = 5 V, T_{amb} = 25 °C (unless otherwise specified)

Symbol	Parameter	Min.	Тур.	Max.	Unit
V _{IO}	Input offset voltage $TS861/2/4$ $T_{min} < T < T_{max}$ $TS861/2/4A$ $T_{min} < T < T_{max}$		3	15 18 7 10	mV
ΔV _{IO}	Input offset voltage drift		6		μV/°C
I _{IO}	Input offset current ⁽¹⁾ T _{min} < T < T _{max}		1	150 300	pA
I _{IB}	Input bias current ⁽¹⁾ T _{min} < T < T _{max}		1	300 600	pA
V _{OH}	High level output voltage $I_{SOURCE} = 5 \text{ mA} \\ T_{min} < T < T_{max}$	4.6 4.45	4.8		٧
V _{OL}	Low level output voltage $I_{SINK} = 5 \text{ mA}$ $T_{min} < T < T_{max}$		0.2	0.4 0.55	٧
A _{VD}	Large signal voltage gain ⁽²⁾		240		dB
CMR	Common mode rejection ratio 0 < V _{ICM} < 5 V		70		dB
SVR	Supply voltage rejection ratio 2.7 < V _{CC} < 10 V		80		dB
I _{CC}	Supply current per comparator No load, output low No load, output high		6 8	12 14	μΑ
T _{PLH}	Propagation delay from output low to output high $V_{ICM} = 2.5 \text{ V}$, $f = 10 \text{ kHz}$, $C_L = 50 \text{ pF}$ Overdrive = 10 mV Overdrive = 100 mV		2 0.5		μs
T _{PHL}	Propagation delay from output high to output low $V_{ICM} = 2.5 \text{ V}$, $f = 10 \text{ kHz}$, $C_L = 50 \text{ pF}$ Overdrive = 10 mV Overdrive = 100 mV		2 0.4		μs
T _F	Fall time $f = 10 \text{ kHz}, C_L = 50 \text{ pF}, \text{ overdrive} = 100 \text{ mV}$		20		ns
T _R	Rise time $f = 10 \text{ kHz}, C_L = 50 \text{ pF, overdrive} = 100 \text{ mV}$		20		ns

^{1.} Maximum values including unavoidable inaccuracies of the industrial test.

Note: Limits are 100% production tested at 25 °C. Limits over temperature are guaranteed through correlation and by design.

577

Doc ID 6422 Rev 3 5/19

^{2.} Design evaluation.

Table 5. Electrical characteristics at V_{CC} = +10 V, T_{amb} = 25 °C (unless otherwise specified)

Symbol	Parameter	Min.	Тур.	Max.	Unit
V _{IO}	Input offset voltage ($V_{ICM} = V_{CC} / 2$) TS861/2/4 $T_{min} < T < T_{max}$		3	15 18	mV
ΔV _{IO}	Input offset voltage drift		6		μV/°C
I _{IO}	Input offset current ⁽¹⁾ $T_{min} < T < T_{max}$		1	150 300	pA
I _{IB}	Input bias current ⁽¹⁾ $T_{min} < T < T_{max}$		1	300 600	pA
V _{OH}	High level output voltage I _{SOURCE} = 5 mA T _{min} < T < T _{max}	9.6 9.45	9.8		V
V _{OL}	Low level output voltage $I_{SINK} = 5 \text{ mA}$ $T_{min} < T < T_{max}$		0.2	0.4 0.55	V
A _{VD}	Large signal voltage gain ⁽²⁾		240		dB
CMR	Common mode rejection ratio 0 < V _{ICM} < 10 V		75		dB
SVR	Supply voltage rejection ratio 2.7 < V _{CC} < 10 V		80		dB
I _{CC}	Supply current per comparator No load, output low No load, output high		7 10	14 16	μА
T _{PLH}	Propagation delay from output low to output high $V_{ICM} = 5 \text{ V}$, $f = 10 \text{ kHz}$, $C_L = 50 \text{ pF}$ Overdrive = 10 mV Overdrive = 100 mV		3 0.5		μs
T _{PHL}	Propagation delay from output high to output low $V_{ICM} = 5 \text{ V}$, $f = 10 \text{ kHz}$, $C_L = 50 \text{ pF}$ Overdrive = 10 mV Overdrive = 100 mV		2.6 0.4		μs
T _F	Fall time $f = 10 \text{ kHz}, C_L = 50 \text{ pF}, \text{ overdrive} = 100 \text{ mV}$		20		ns
T _R	Rise time f = 10 kHz, C _L = 50 pF, overdrive = 100 mV		20		ns

^{1.} Maximum values including unavoidable inaccuracies of the industrial test.

Note: Limits are 100% production tested at 25 °C. Limits over temperature are guaranteed through correlation and by design.

577

^{2.} Design evaluation.

Figure 1. V_{IO} vs. V_{ICM} at V_{CC} = 2.7 V

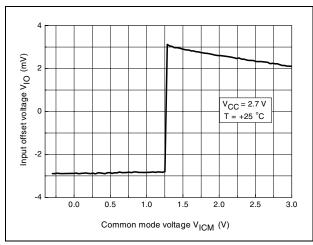


Figure 2. V_{IO} vs. V_{ICM} and temperature at V_{CC} = 2.7 V

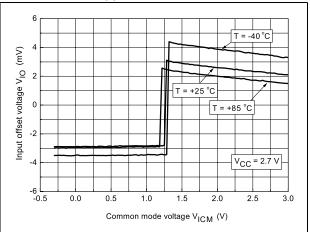


Figure 3. V_{IO} vs. V_{ICM} at $V_{CC} = 5$ V

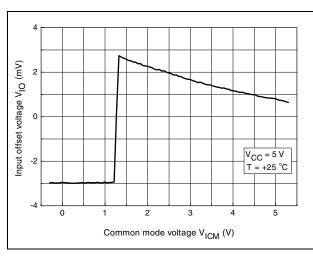


Figure 4. V_{IO} vs. V_{ICM} and temperature at V_{CC} = 5 V

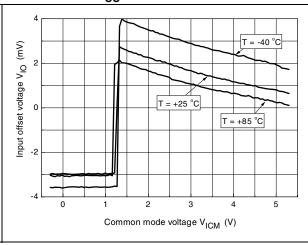


Figure 5. V_{IO} vs. V_{ICM} at V_{CC} = 10 V

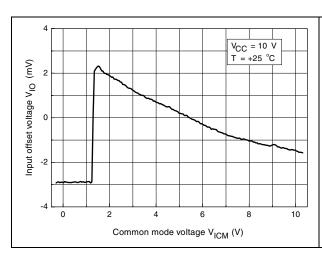
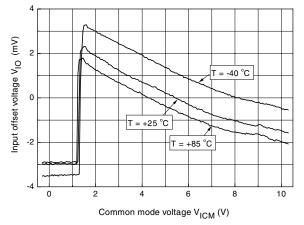


Figure 6. V_{IO} vs. V_{ICM} and temperature at V_{CC} = 10 V



577

Doc ID 6422 Rev 3

 V_{IO} vs. V_{CC} at $V_{ICM} = V_{CC}/2$ Figure 7.

Input offset voltage V_{IO} (mV) V_{ICM} = V_{CC}/2 T = +25 °C 3 5 10 Supply voltage V_{CC} (V)

 V_{IO} vs. temperature at V_{CC} = 5 V Figure 8.

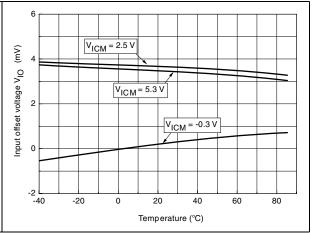


Figure 9. Supply current (I_{CC}) vs. supply voltage $(V_{CC}) (V_{ID} = -1 V)$

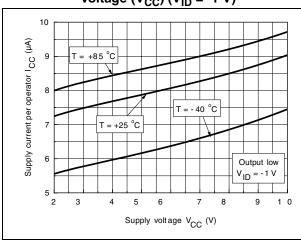


Figure 10. Supply current (I_{CC}) vs. supply voltage $(V_{CC})(V_{ID} = +1 V)$

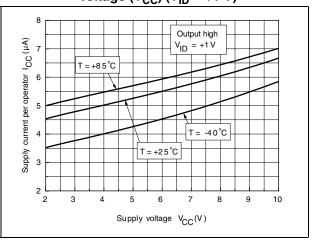


Figure 11. Supply current (I_{CC}) vs. temperature $(V_{ID} = -1 V)$

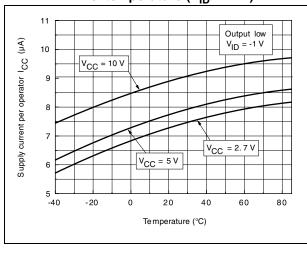
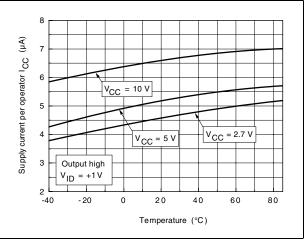


Figure 12. Supply current (I_{CC}) vs. temperature ($V_{ID} = +1 V$)



8/19 Doc ID 6422 Rev 3

Figure 13. V_{OL} vs. I_{SINK} and temperature at V_{CC} = 5 V

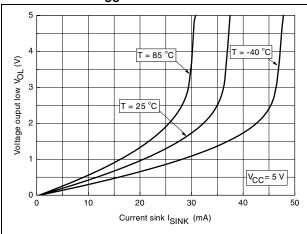


Figure 14. V_{OH} vs. I_{SOURCE} and temperature at V_{CC} = 5 V

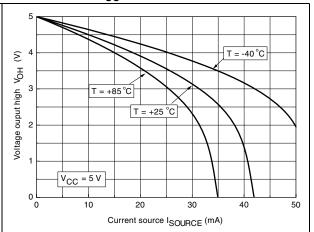


Figure 15. Propagation delay T_{PLH} vs. V_{ICM} with $V_{OVD} = 100 \text{ mV}$

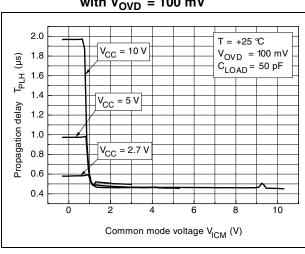


Figure 16. Propagation delay T_{PHL} vs. V_{ICM} with $V_{OVD} = 100 \text{ mV}$

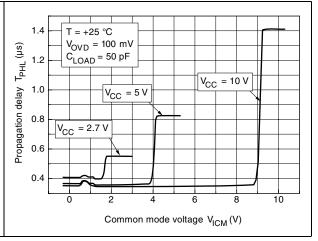


Figure 17. Propagation delay T_{PLH} vs. V_{ICM} with $V_{OVD} = 10 \text{ mV}$

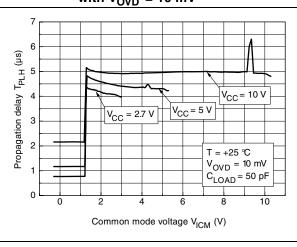
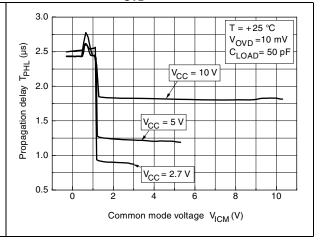


Figure 18. Propagation delay T_{PHL} vs. V_{ICM} with $V_{OVD} = 10 \text{ mV}$



577

Doc ID 6422 Rev 3

Figure 19. Propagation delay vs. V_{CC} with $V_{OVD} = 10 \text{ mV}$

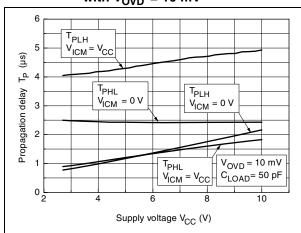


Figure 20. Propagation delay vs. V_{CC} with $V_{OVD} = 100 \text{ mV}$

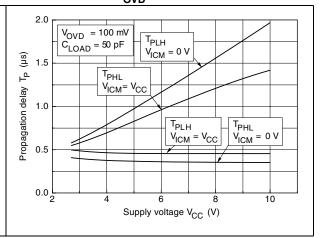


Figure 21. Propagation delay vs. overdrive voltage at $V_{CC} = 2.7 \text{ V}$

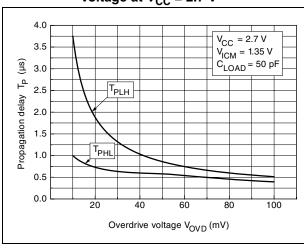


Figure 22. Propagation delay vs. overdrive voltage at $V_{CC} = 5 \text{ V}$

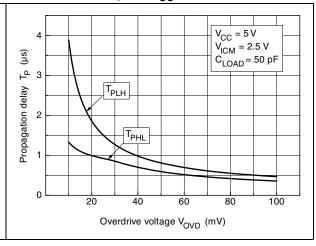
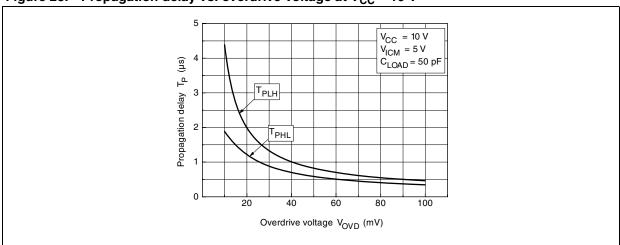


Figure 23. Propagation delay vs. overdrive voltage at V_{CC} = 10 V



10/19 Doc ID 6422 Rev 3

3 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

3.1 SOT23-5 package information

Figure 24. SOT23-5L package outline

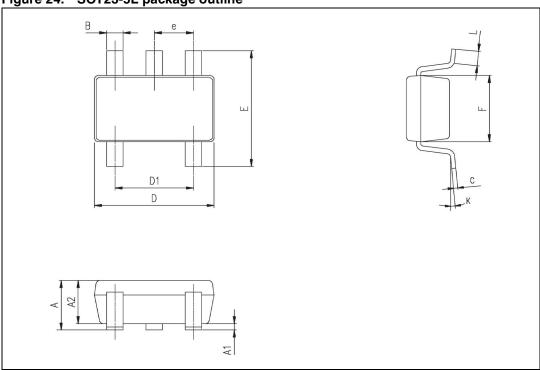


Table 6. SOT23-5L package mechanical data

	Dimensions							
Symbol		Millimeters			Inches			
	Min.	Тур.	Max.	Min.	Тур.	Max.		
А	0.90	1.20	1.45	0.035	0.047	0.057		
A1			0.15			0.006		
A2	0.90	1.05	1.30	0.035	0.041	0.051		
В	0.35	0.40	0.50	0.013	0.015	0.019		
С	0.09	0.15	0.20	0.003	0.006	0.008		
D	2.80	2.90	3.00	0.110	0.114	0.118		
D1		1.90			0.075			
е		0.95			0.037			
Е	2.60	2.80	3.00	0.102	0.110	0.118		
F	1.50	1.60	1.75	0.059	0.063	0.069		
L	0.10	0.35	0.60	0.004	0.013	0.023		
K	0°		10°					

3.2 SO-8 package information

Figure 25. SO-8 package outline

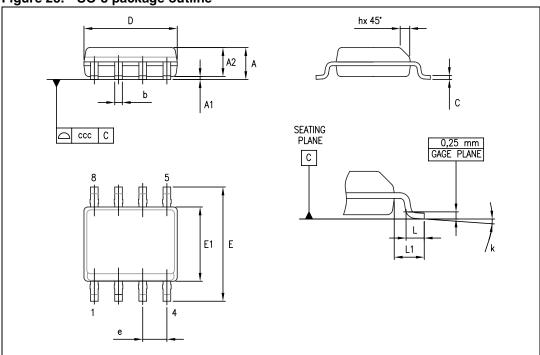


Table 7. SO-8 package mechanical data

	Dimensions						
Symbol		Millimeters			Inches		
	Min.	Тур.	Max.	Min.	Тур.	Max.	
А			1.75			0.069	
A1	0.10		0.25	0.004		0.010	
A2	1.25			0.049			
b	0.28		0.48	0.011		0.019	
С	0.17		0.23	0.007		0.010	
D	4.80	4.90	5.00	0.189	0.193	0.197	
Е	5.80	6.00	6.20	0.228	0.236	0.244	
E1	3.80	3.90	4.00	0.150	0.154	0.157	
е		1.27			0.050		
h	0.25		0.50	0.010		0.020	
L	0.40		1.27	0.016		0.050	
L1		1.04			0.040		
k	0		8°	1°		8°	
ccc			0.10			0.004	

5/

Doc ID 6422 Rev 3

3.3 SO-14 package information

Figure 26. SO-14 package outline

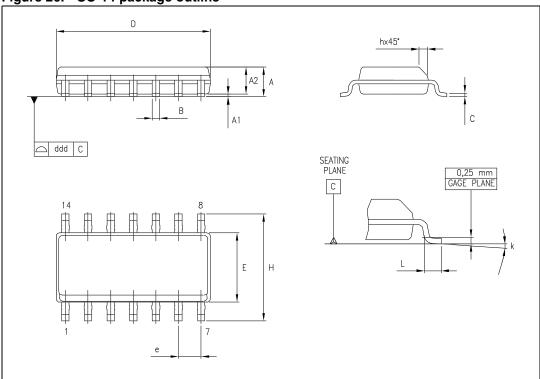


Table 8. SO-14 package mechanical data

	Dimensions						
Symbol	Millimeters			Inches			
	Min.	Тур.	Max.	Min.	Тур.	Max.	
Α	1.35		1.75	0.05		0.068	
A1	0.10		0.25	0.004		0.009	
A2	1.10		1.65	0.04		0.06	
В	0.33		0.51	0.01		0.02	
С	0.19		0.25	0.007		0.009	
D	8.55		8.75	0.33		0.34	
E	3.80		4.0	0.15		0.15	
е		1.27			0.05		
Н	5.80		6.20	0.22		0.24	
h	0.25		0.50	0.009		0.02	
L	0.40		1.27	0.015		0.05	
k	8° (max.)						
ddd			0.10			0.004	

57

3.4 TSSOP8 package information

Figure 27. TSSOP8 package outline

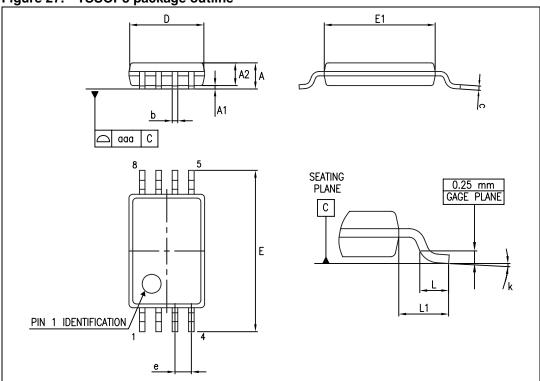


Table 9. TSSOP8 package mechanical data

	Dimensions						
Symbol	Millimeters			Inches			
	Min.	Тур.	Max.	Min.	Тур.	Max.	
Α			1.20			0.047	
A1	0.05		0.15	0.002		0.006	
A2	0.80	1.00	1.05	0.031	0.039	0.041	
b	0.19		0.30	0.007		0.012	
С	0.09		0.20	0.004		0.008	
D	2.90	3.00	3.10	0.114	0.118	0.122	
Е	6.20	6.40	6.60	0.244	0.252	0.260	
E1	4.30	4.40	4.50	0.169	0.173	0.177	
е		0.65			0.0256		
k	0°		8°	0°		8°	
L	0.45	0.60	0.75	0.018	0.024	0.030	
L1		1			0.039		
aaa			0.10			0.004	

57

Doc ID 6422 Rev 3 15/19

3.5 TSSOP14 package information

Figure 28. TSSOP14 package outline

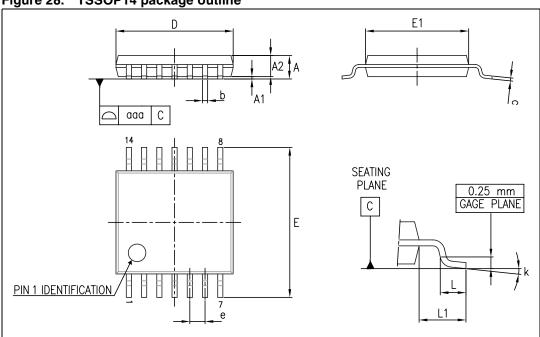


Table 10. TSSOP14 package mechanical data

	Dimensions						
Symbol	Millimeters				Inches		
-	Min.	Тур.	Max.	Min.	Тур.	Max.	
Α			1.20			0.047	
A1	0.05		0.15	0.002	0.004	0.006	
A2	0.80	1.00	1.05	0.031	0.039	0.041	
b	0.19		0.30	0.007		0.012	
С	0.09		0.20	0.004		0.0089	
D	4.90	5.00	5.10	0.193	0.197	0.201	
Е	6.20	6.40	6.60	0.244	0.252	0.260	
E1	4.30	4.40	4.50	0.169	0.173	0.176	
е		0.65			0.0256		
L	0.45	0.60	0.75	0.018	0.024	0.030	
L1		1.00			0.039		
k	0°		8°	0°		8°	
aaa			0.10			0.004	

4 Ordering information

Table 11. Order codes

Part number	Temperature range	Package	Packaging	Marking
TS861ILT TS861AILT	-40 °C, +85 °C	SOT-23	Tape and reel	K501 K502
TS861ID TS861IDT		SO-8	Tube Tape and reel	8611
TS861AID TS861AIDT		1AID	30-6	Tube Tape and reel
TS862ID TS862IDT		SO-8	Tube Tape and reel	8621
TS862AID TS862AIDT	-40 °C, +85 °C	30-6	Tube Tape and reel	862AI
TS862IPT TS862AIPT		TSSOP8	Tape and reel	862I 862AI
TS864ID TS864IDT		SO-14	Tube Tape and reel	8641
TS864AID TS864AIDT	-40 °C, +85 °C	30-14	Tube Tape and reel	864AI
TS864IPT TS864AIPT		TSSOP14	Tape and reel	864I 864AI

Revision history TS861, TS862, TS864

5 Revision history

Table 12. Document revision history

Date	Revision	Changes
01-Feb-2002	1	Initial release.
28-Apr-2009	2	Updated document format. Removed power dissipation from <i>Table 1: Absolute maximum ratings</i> . Added Rthja and Rthjc values and ESD notes in <i>Table 1</i> . Updated curves in <i>Figure 1</i> to <i>Figure 14</i> . Changed <i>Figure 15</i> , <i>Figure 16</i> , <i>Figure 17</i> and <i>Figure 18</i> . Added <i>Figure 19</i> , <i>Figure 20</i> , <i>Figure 21</i> , <i>Figure 22</i> and <i>Figure 23</i> . Removed DIP package information in <i>Chapter 3</i> and <i>Chapter 4</i> . Added ordering information in <i>Table 11: Order codes</i> .
06-Nov-2012	3	Updated titles of <i>Figure 9</i> to <i>Figure 12</i> (added conditions). Removed TS861IYLT, TS861AIYLT, TS862IYDT, TS862IYDT, TS864IYDT, and TS864AIYDT order codes from <i>Table 11</i> . Minor corrections throughout document.

Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

UNLESS EXPRESSLY APPROVED IN WRITING BY TWO AUTHORIZED ST REPRESENTATIVES, ST PRODUCTS ARE NOT RECOMMENDED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE. ST PRODUCTS WHICH ARE NOT SPECIFIED AS "AUTOMOTIVE GRADE" MAY ONLY BE USED IN AUTOMOTIVE APPLICATIONS AT USER'S OWN RISK.

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2012 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Philippines - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com

577

Doc ID 6422 Rev 3 19/19